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BLF7G24L-160P; BLF7G24LS-160P Power LDMOS transistor Rev. 6 — 1 September 2015

AMMPLEON

Product data sheet

Product profile

1.1 General description

160 W LDMOS power transistor for base station applications at frequencies from 2300 MHz to 2400 MHz.

Typical performance Table 1.

Typical RF performance at $T_{case} = 25$ °C in a common source class-AB production test circuit.

Test signal	f	I _{Dq}	V _{DS}	$P_{L(AV)}$	Gp	η_D	ACPR _{885k}
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)
IS-95	2300 to 2400	1200	28	30	18.5	27.5	-45.5 ^[1]

^[1] Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R_{th} providing excellent thermal stability
- Designed for broadband operation (2300 MHz to 2400 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 2300 MHz to 2400 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outlin	ne Graphic symbol
BLF7G24	L-160P (SOT539A)		
1	drain1		
2	drain2	1 2	1 ¬
3	gate1		⁵ 3 1
4	gate2	3 4	5
5	source	[1]	4
			' <u></u>
			2 svm117
			SVM11/

BLF7G2	4LS-160P (SOT539B)			
1	drain1			
2	drain2		1 2	1 ا
3	gate1		5	ا ا
4	gate2		3 4	3 - 5
5	source	[1]		4
				"-
				2 sym117

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BLF7G24L-160P	-	flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A			
BLF7G24LS-160P	-	earless flanged balanced ceramic package; 4 leads	SOT539B			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	200	°C

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$R_{\text{th(j-c)}}$	thermal resistance from junction to case	T_{case} = 80 °C; P_L = 30 W; V_{DS} = 28 V; I_{Dq} = 1200 mA	0.2	K/W

6. Characteristics

Table 6. Characteristics

 $T_i = 25$ °C per section, unless otherwise specified.

J	j == o per dediteri, umade dirierinica apadimati.					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 1 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 102 mA	1.5	1.9	2.3	V
I _{DSS}	drain leakage current	V_{GS} = 0 V; V_{DS} = 28 V	-	-	2.8	μА
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	19	-	Α
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	280	nΑ
9 _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 3.57 A	-	6.9	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 3.57 \text{ A}$	-	0.15	0.23	Ω

7. Test information

Remark: All testing performed in a class-AB production test circuit.

Table 7. Functional test information

Test signal: single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF, channel bandwidth is 1.2288 MHz; f_1 = 2300 MHz; f_2 = 2400 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 1200 mA; T_{case} = 25 °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	$P_{L(AV)} = 30 W$	17.8	18.5	-	dB
RLin	input return loss	$P_{L(AV)} = 30 W$	-	-13.5	-9	dB
η_{D}	drain efficiency	$P_{L(AV)} = 30 W$	25	27.5	-	%
ACPR _{885k}	adjacent channel power ratio (885 kHz)	$P_{L(AV)} = 30 W$	-	-45.5	-41.5	dBc

7.1 Ruggedness in class-AB operation

The BLF7G24L-160P and BLF7G24LS-160P are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28 \text{ V}$; $I_{Dq} = 1200 \text{ mA}$; $P_L = 160 \text{ W}$; f = 2300 MHz.

7.2 Impedance information

Table 8. Typical impedance

Measured load-pull data. Typical values per section. $I_{Da} = 600 \text{ mA}$; main transistor $V_{DS} = 28 \text{ V. } Z_S$ and Z_L defined in Figure 1.

f (MHz)	Z _S (Ω)	Z _L (Ω)
2300	2.5 – j5.9	3.1 – j4.3
2400	4.6 – j7.2	2.9 – j4.2

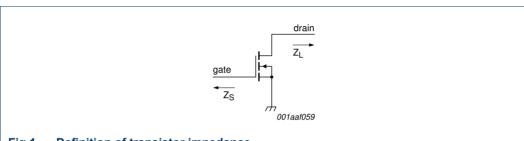
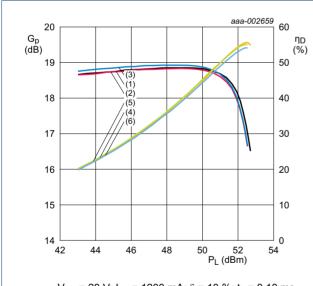


Fig 1. Definition of transistor impedance

7.3 Graphs

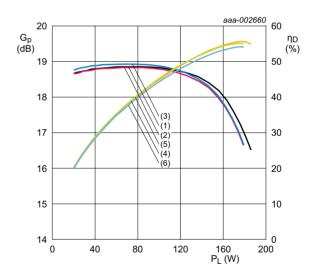
7.3.1 Pulsed CW



 V_{DS} = 28 V; I_{Dq} = 1200 mA; δ = 10 %; t_p = 0.10 ms.

- (1) G_p at f = 2300 MHz
- (2) G_p at f = 2350 MHz
- (3) G_p at f = 2400 MHz
- (4) η_D at f = 2300 MHz
- (5) η_D at f = 2350 MHz
- (6) η_D at f = 2400 MHz

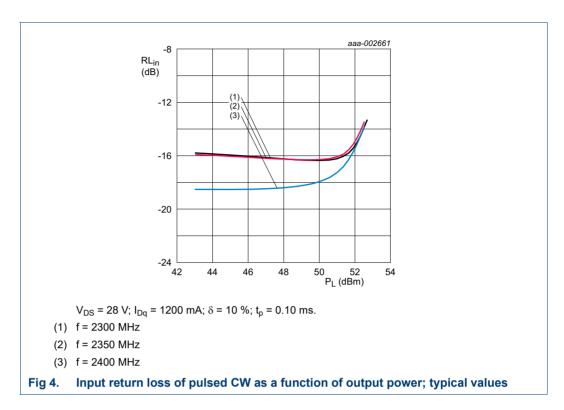
Fig 2. Power gain and drain efficiency of pulsed CW as function of output power; typical values



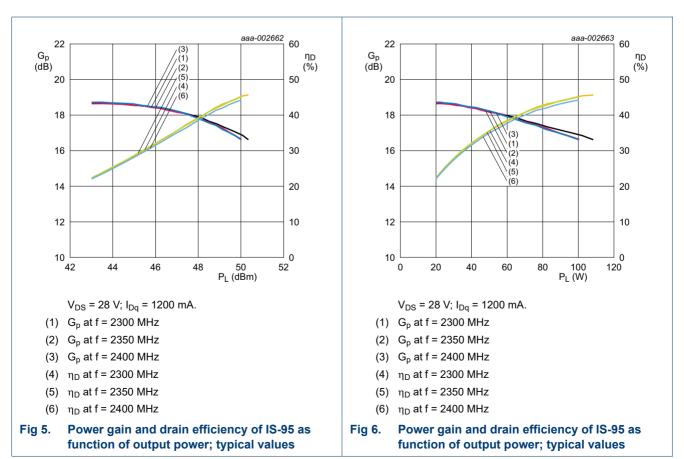
 V_{DS} = 28 V; I_{Dq} = 1200 mA; δ = 10 %; t_p = 0.10 ms.

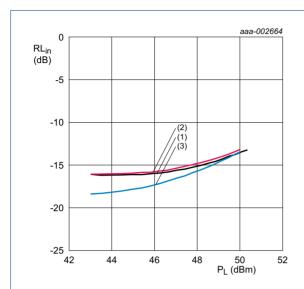
- (1) G_p at f = 2300 MHz
- (2) G_p at f = 2350 MHz
- (3) G_p at f = 2400 MHz
- (4) η_D at f = 2300 MHz
- (5) η_D at f = 2350 MHz
- (6) η_D at f = 2400 MHz

Fig 3. Power gain and drain efficiency of pulsed CW as function of output power; typical values



7.3.2 IS-95

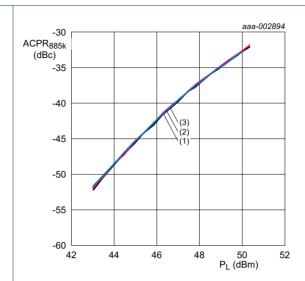




 $V_{DS} = 28 \text{ V}; I_{Dq} = 1200 \text{ mA}.$

- (1) f = 2300 MHz
- (2) f = 2350 MHz
- (3) f = 2400 MHz

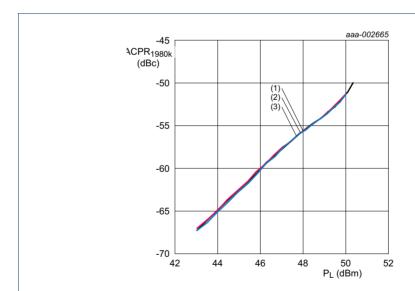
Fig 7. Input return loss of IS-95 as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1200 \text{ mA}.$

- (1) f = 2300 MHz
- (2) f = 2350 MHz
- (3) f = 2400 MHz

Fig 8. Adjacent channel power ratio (885 kHz) of IS-95 as a function of output power; typical values

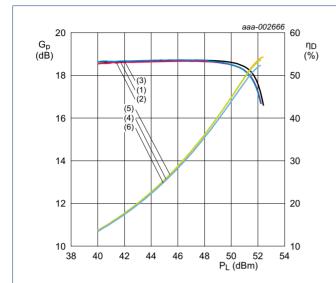


 $V_{DS} = 28 \text{ V}; I_{Dq} = 1200 \text{ mA}.$

- (1) f = 2300 MHz
- (2) f = 2350 MHz
- (3) f = 2400 MHz

Fig 9. Adjacent channel power ratio (1980 kHz) of IS-95 as a function of output power; typical values

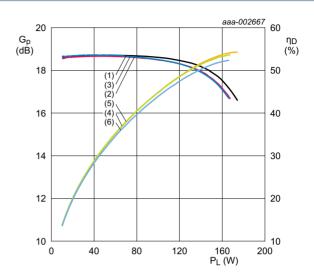
7.3.3 CW



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1200 \text{ mA}.$

- (1) G_p at f = 2300 MHz
- (2) G_p at f = 2350 MHz
- (3) G_p at f = 2400 MHz
- (4) η_D at f = 2300 MHz
- (5) η_D at f = 2350 MHz
- (6) η_D at f = 2400 MHz

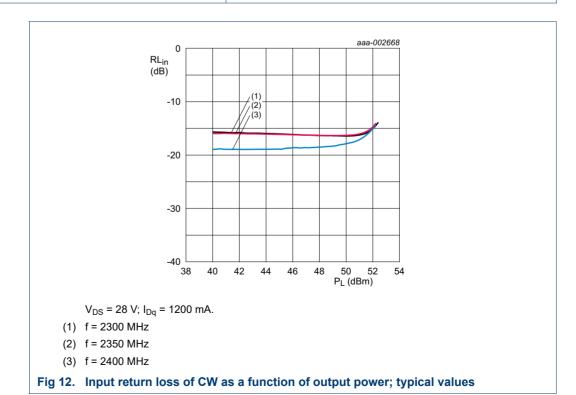
Fig 10. Power gain and drain efficiency of CW as function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 1200 \text{ mA}.$

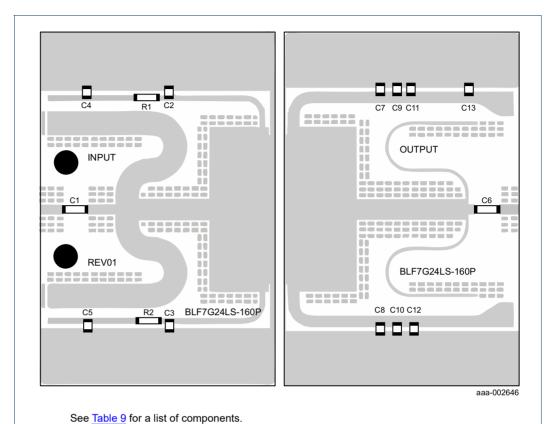
- (1) G_p at f = 2300 MHz
- (2) G_p at f = 2350 MHz
- (3) G_p at f = 2400 MHz
- (4) η_D at f = 2300 MHz
- (5) η_D at f = 2350 MHz
- (6) η_D at f = 2400 MHz

Fig 11. Power gain and drain efficiency of CW as function of output power; typical values



BLF7G24L-160P_7G24LS-160P#6

7.4 Test circuit



See Table 9 for a list of components.

Fig 13. Component layout for test circuit

Table 9. List of components For test circuit, see Figure 13.

Remarks
<u>[1]</u>
[2]
<u>[1]</u>
<u>[3]</u>

- [1] American technical ceramics type 100B or capacitor of same quality.
- [2] American technical ceramics type 100A or capacitor of same quality.
- [3] TDK or capacitor of same quality.

8. Package outline

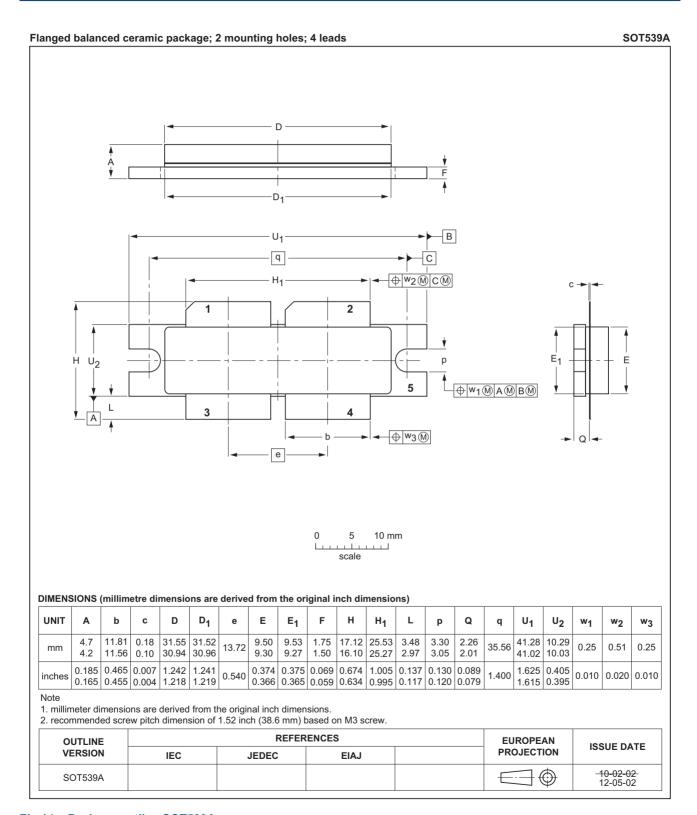


Fig 14. Package outline SOT539A

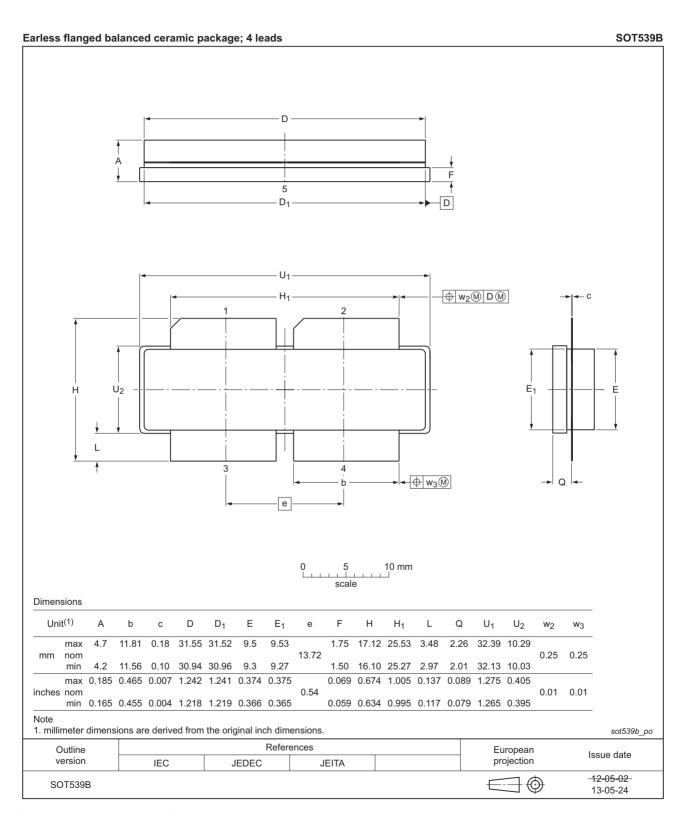


Fig 15. Package outline SOT539B

9. Abbreviations

Table 10. Abbreviations

Acronym	Description
CCDF	Complementary Cumulative Distribution Function
IS-95	Interim Standard 95
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal Oxide Semiconductor
PAR	Peak-to-Average Ratio
RF	Radio Frequency
VSWR	Voltage Standing Wave Ratio

10. Revision history

Table 11. Revision history

Document ID	Release date		Change notice	Supersedes
BLF7G24L-160P_7G24LS-160P#6	20150901	Product data sheet	-	BLF7G24L-160P_7G24LS-160P v.5
Modifications:	 The format of this document has been redesigned to comply with the new in guidelines of Ampleon. Legal texts have been adapted to the new company name where approprise 			
BLF7G24L-160P_7G24LS-160P v.5		Product data sheet	_	BLF7G24L-160P_7G24LS-160P v.4
BLF7G24L-160P_7G24LS-160P v.4	20120725	Product data sheet	-	BLF7G24L-160P_7G24LS-160P v.3
BLF7G24L-160P_7G24LS-160P v.3	20120420	Preliminary data sheet	-	BLF7G24L-160P_7G24LS-160P v.2
BLF7G24L-160P_7G24LS-160P v.2	20120301	Objective data sheet	-	BLF7G24L-160P_7G24LS-160P v.1
BLF7G24L-160P_7G24LS-160P v.1	20120210	Objective data sheet	-	-

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Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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- [2] The term 'short data sheet' is explained in section "Definitions"
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Power LDMOS transistor

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Power LDMOS transistor

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